-	/
ſA	7
и	1

	Application No.	Applicant(s)		
Notice of Allowability	10/633,981	FUSELIER ET AL.		
	Examiner	Art Unit		
* *	Walter L. Lindsay, Jr.	2812		
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate community IGHTS. This application is su	this application. If not include	ed	
1. This communication is responsive to	``			
2. The allowed claim(s) is/are <u>1-29</u> .			•	
3. The drawings filed on 8/30/2004 are accepted by the Exam	niner.			
attached Examiner's comment regarding REQUIREMENT (	ON THE BET OON OF BIOL	OGICAL WATERIAL.		
Attachm nt(s)		*		
1. Notice of References Cited (PTO-892)	5. Notice of Infor	mal Patent Application (PTC	-152)	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. Interview Sum	nmary (PTO-413),		
3. Information Disclosure Statements (PTO-1449 or PTO/SB/06 Paper No./Mail Date	Paper No./Ma 8), 7. ☐ Examiner's Ar	Paper No./Mail Date		
4. Examiner's Comment Regarding Requirement for Deposit		atement of Reasons for Allov	vance	
of Biological Material	9. 🗌 Other			
	•			

Application/Control Number: 10/633,981

Art Unit: 2812

## **DETAILED ACTION**

## Allowable Subject Matter

- 1. Claims 1-29 are allowed.
- 2. The following is an examiner's statement of reasons for allowance: the prior art, either singly or in combination fails to anticipate or render obvious, the limitations of:

substrate, wherein the sidewall layer comprises a first portion overlying a first sidewall of the gate structure;

forming a photoresist structure adjacent to the first portion; and subjecting the photoresist structure to an ion beam, wherein the photoresist structure shields at least part of the first portion from the ion beam, as required by claim 1.

The prior art, either singly or in combination fails to anticipate or render obvious, the limitations of:

In forming a sidewall layer overlying the first gate structure, wherein the sidewall layer comprises a first sidewall layer portion overlying the first side, and a second sidewall layer portion overlying the second side; and

subjecting the first sidewall layer portion to an ion dose while the second sidewall layer portion is not subjected to the ion dose, as required by claim 13.

Lastly the prior art, either singly or in combination fails to anticipate or render obvious, the limitations of:

Application/Control Number: 10/633,981

Art Unit: 2812

... adjusting a tilt between an ion beam path and the plurality of gate structures to comprise a directional component in the second direction;

subjecting the first side of a second plurality of gate structures to a first ion dose, wherein the second plurality of gate structures is a subset of the first plurality of gate structures that is less than the first plurality of gate structures, as required by claim 23.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

## Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Walter L. Lindsay, Jr. whose telephone number is (571) 272-1674. The examiner can normally be reached on Monday-Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John F Niebling can be reached on (571) 272-1679. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Art Unit: 2812

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

WLL Noll L. Lindays May 12, 2004 Ha Tran Nguyen Primary Examiner Technology Center 2800